

# APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS
Capacitor Arrays Series (10V to 100V)
4 x 0402, 4 x 0603 Sizes
NP0, X7R & Y5V Dielectrics
Halogen Free & RoHS Compliance

<sup>\*</sup>Contents in this sheet are subject to change without prior notice.

## 1. INTRODUCTION

WTC middle and high voltage series MLCC is designed by a special internal electrode pattern, which can reduce voltage concentrations by distributing voltage gradients throughout the entire capacitor. This special design also affords increased capacitance values in a given case size and voltage rating.

WTC capacitor arrays are developed to offer designers the opportunity to lower placement costs increase assembly line output through lower component count per board.

#### 2. FEATURES

- a. High density mounting due to mounting space saving.
- b. Mounting cost saving.
- c. Increased throughput.

## 3. APPLICATIONS

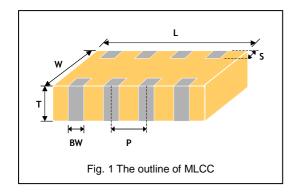
- For use as a bypass for digital and analog signal line noise
- b. Computer motherboards and peripherals.
- c. The other common electronic circuits.

## **4. HOW TO ORDER**

				1+	12			
<u>Y</u>	<u>4C</u>	<u>3</u>	<u>B</u>	<u>103</u>	<u>K</u>	<u>500</u>	<u>C</u>	I
<u>Series</u>	Cap. Nr.	Termination pitch	<u>Dielectric</u>	Capacitance	Tolerance	Rated voltage	<u>Termination</u>	<u>Packaging</u>
Y=Capacitor array	<b>4C</b> =4xCap	<b>3</b> =0.03" pitch* <b>2</b> =0.02" pitch*	N=NP0 (C0G)	digits followed	<b>J</b> =±5% <b>K</b> =±10%	Two significant digits followed	<b>C</b> =Cu/Ni/Sn	T=7" reeled
			<b>B</b> =X7R <b>F</b> =Y5V	by no. of zeros. And R is in	<b>Z</b> =-20/+80%	by no. of zeros. And R is in		
Y	/4C3: 4x060	3 (0612)	NO PAS	place of decimal point.	LLIANCE	place of decimal point.		
Y	/4C2: 4x040	2 (0508)		eg.: 103=10x10 <sup>3</sup> =10,000pF	Cologic	eg.: 100=10 VDC 160=16 VDC		
			The state of the s	7/NO 10nF CORPC	RATION. FL	250=25 VDC 500=50 VDC 101=100 VDC		

<sup>\*</sup>Size/ Inch (mm): 4x0402=0508 (1220), 4x0603=0612 (1632)

#### 5. EXTERNAL DIMENSIONS



Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbol		S (mm)	BW (mm)	P (mm)	
4x0402 0508 (1220)	2.00±0.15	1.25±0.15	0.85±0.10	Т	0.20±0.10	0.25±0.10	0.50±0.10	
4x0603 0612 (1632)	3.20±0.15	1.60±0.15	0.80±0.10	В	0.30±0.20	0.40±0.15	0.80±0.15	

Reflow soldering process only.

## **6. GENERAL ELECTRICAL DATA**

	144117	A				
Dielectric	, NF	90	X7	X7R		
Size	4x0402 4x0603		4x0402	4x0603	4x0603	
Inch (mm)	0508 (1220)	0612 (1632)	0508 (1220)	0612 (1632)	0612 (1632)	
Capacitance*	10pF to 270pF	=10pF to 470pF∈	1000pF to 100nF	150pF to 100nF	10nF to 100nF	
Capacitance tolerance**	J (±5%), K (±10%)		K (±10%),	Z (-20/+80%)		
Rated voltage (WVDC)	25, 50V, 100V		10V, 16V, 25V, 50V	16V, 25V, 50V	16V, 50V	
Q/Tan δ*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000		Ur=50V Ur=25V&1 Ur=10V	Ur=50V, ≤5% Ur=16V, ≤7%		
Insulation resistance at Ur	≥10	GOCHIDION	10GΩ ≥10GΩ	chever is less		
Operating temperature		55 to	) +125℃	-25 to +85℃		
Capacitance characteristic	±30ppm		±15%		+30/-80%	
Termination			Ni/Sn (lead-free term	nination)		

<sup>\*</sup> Measured at 30~70% related humidity.

NP0: Apply 1.0±0.2Vrms, 1.0MHz±10% at the conditions of 25℃ ambient temperature.

X7R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 25℃ ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 20℃ ambient temperature.

<sup>\*\*</sup> Preconditioning for Class II MLCC: Perform a heat treatment at 150±10°C for 1 hour, then leave in a mbient condition for 24±2 hours before measurement.

## 7. CAPACITANCE RANGE

SIZE Inch (mm)			0	4 x 040 0508 (12					4x0603 0612 (1632)							
D	DIELECTRIC		NP0 X7R			NPO X7R				Y5V						
RAT	ED VOLTAGE (VDC)	25	50	100	10	16	25	50	25	50	100	16	25	50	16	50
	10pF (100)	Т	Т	Т					В	В	В					
	15pF (150)	Т	Т	Т					В	В	В					
	22pF (220)	Т	Т	Т					В	В	В					
	33pF (330)	Т	Т	Т					В	В	В					
	47pF (470)	Т	Т	Т					В	В	В					
	68pF (680)	Т	Т	Т					В	В	В					
	100pF (101)	Т	Т	Т					В	В	В					
	120pF (121)	Т	Т	Т					В	В	В					
	150pF (151)	Т	Т	Т					В	В	В		В	В		
	180pF (181)	Т	Т	Т					В	В	В		В	В		
	220pF (221)	Т	Т	Т					В	В	В		В	В		
	270pF (271)	Т	Т	Т					В	В	В		В	В		
20	330pF (331)								В	В	В		В	В		
itar	470pF (471)								В	В	В		В	В		
Capacitance	6,80pF (681)												В	В		
Sa	1,000pF (102)				Т	T	727	ET	13				В	В		
	1,500pF (152)				Т	E	77	T	R	Bil			В	В		
	2,200pF (222)				T	/TO	江	财化	7×	11/	1		В	В		
	3,300pF (332)				T,	T 🗸	$\searrow$ Ť $\!$	ルケイ	<b>13</b>	众	Tal		В	В		
	4,700pF (472)				143/17	,T<	T	Т	*	F	791		В	В		
	6,800pF (682)				T <sup>r</sup>	$\mu$	Т	Т		<b>V</b> /			В	В		
	0.010µF (103)				Т	41	I	프	Λ		7		В	В		В
	0.015µF (153)				Т	Т	Т		A			В	В	В		В
	0.022µF (223)				g.	TPA		SYSTEM	ALLIA	NCE		В	В	В		В
	0.033µF (333)				3	<b>_T</b>	Т			2.		В				В
	0.047µF (473)				1	T.	Т			7.8	\$3	В				В
	0.068µF (683)				T	) T	1			0	85/	В				В
	0.10µF (104)				T	T	O.T.		CO	1	5	В			В	В

<sup>1.</sup> The letter in cell is expressed the symbol of product thickness.

## **8. PACKAGING DIMENSION AND QUANTITY**

SIZE	SIZE Thickness/Symb		Pap	iper tape		
Inch (mm)	(mm)		7" reel	13" reel		
4x0402	0.85±0.10	т	4k	-		
0508 (1220)	0.03±0.10	'	46			
4x0603	0.00.040	Б	41-	-		
0612 (1632)	0.80±0.10	В	4k			

Unit: pieces



## 9. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

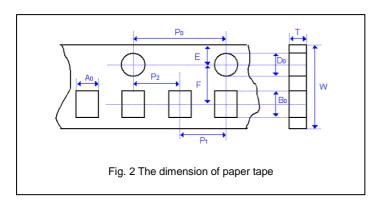
No.	Item		Test Condition		Requirements			
1.	Visual and				* No remar	kable defect.		
	Mechanical				* Dimensio	ns to conform to individual specification sheet.		
2.	Capacitance	Class I: (NP0	))		* Shall not exceed the limits given in the detailed spec.			
3.	Q/ D.F.	1.0±0.2Vrms	•		NP0: Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C			
	(Dissipation	Class II: (X7F	R, Y5V)		X7R: Ur=50V, ≤2.5%; Ur=25V&16V, ≤3.5%; Ur=10V, ≤5.0%			
	Factor)	1.0±0.2Vrms, 1kHz±10%			•	=50V, ≤5%; Ur=16V, ≤7%		
	,	*Before initial measurement (Class II only): To apply de-aging						
		at 150℃ for 1	Ihr then set for 24±2 hrs at room	emp.				
4.	Dielectric	* To apply 25	0% rated voltage.		* No evide	nce of damage or flash over during test.		
	Strength	* Duration: 1	<del>-</del>			· ·		
		* Charge and	discharge current less than 50m	A.				
_								
5.	Insulation	1 1 1	d voltage for max. 120 sec.		≥10GΩ or l	RxC≥500Ω-F whichever is smaller.		
	Resistance	§	I measurement (Class II only): To					
_		•	thr then set for 24±2 hrs at room	emp.				
6.	Temperature	With no elect		1	то.	Considerate Character		
	Coefficient	T.C. NP0	Operating Temp -55~125℃ at 25℃	-	T.C. NP0	Capacitance Change		
		X7R	-55~125℃ at 25℃	+	X7R	Within ±30ppm/℃ Within ±15%		
		Y5V	-25~85℃ at 20℃	月 7	Y5V	Within +30%/-80%		
		*Before initial	I measurement (Class II only): To	apply de-aging	1110			
		at 150℃ for 1	hr then set for 24±2 hrs at room	emp X // 1	705			
7.	Adhesive	* Pressurizin	g force :		* No remar	kable damage or removal of the terminations.		
	Strength of	5N (≤0603) a	nd 10N (>0603)			51.		
	Termination	* Test time: 1	0±1 sec.		Ū			
8.	Vibration	* Vibration fre	equency: 10~55 Hz/min.		* No remar	kable damage.		
	Resistance	* Total amplitude: 1.5mm PASSIVE SYSTEM AL			* Cap char	nge and Q/D.F.: To meet initial spec.		
		* Test time: 6	hrs. (Two hrs each in three mutu	ally	A			
		perpendicula	r directions.)		1			
		*Before initial	I measurement (Class II only): To	apply de-aging	- 350			
		at 150℃ for 1	hr then set for 24±2 hrs at room	emp.	46			
		*Cap./DF(Q)	Measurement to be made after de	e-aging at 150℃				
		for 1hr then set for 24±2 hrs at room temp.			4011			
9.	Solderability	* Solder temperature: 235±5°C			95% min. o	coverage of all metalized area.		
			e: 2±0.5 sec.		<u> </u>			
10.	Bending Test	Ē	part of substrate shall be pressur		Ĭ.	rkable damage.		
		:	rizing rod at a rate of about 1 mm	-				
		<u> </u>	becomes 1 mm and then the pre	essure shall be				
		maintained fo		onnh '	X7R: within ±12.5%			
		*Before initial measurement (Class II only): To apply de-aging						
		at 150°C for 1hr then set for 24±2 hrs at room temp.			(This capacitance change means the change of capacitance und			
		*Measurement to be made after keeping at room temp. for 24±2 hrs.			the test.)	exure of substrate from the capacitance measured before		
11.	Resistance to	:	nerature: 260+5℃		•	rkable damage.		
		* Solder temperature: 260±5°C t * Dipping time: 10±1 sec			* Cap char			
	Joined IIIg rieal	** Dipping time: 10±1 sec  ** Preheating: 120 to 150°C for 1 minute before imme rse the			•	nge. nin ±2.5% or ±0.25pF whichever is larger.		
			a eutectic solder.			nin ±2.5% of ±0.25pF whichever is larger.		
			I measurement (Class II only): To	apply de-aging	Y5V: with			
		•	Thr then set for 24±2 hrs at room			R. and dielectric strength: To meet initial requirements.		
			) / I.R. Measurement to be made	-		- · · · · · · · · · · · · · · · · · · ·		
			then set for 24±2 hrs at room ten		_5/6 max			
		: .00 0 101 1111	dot to: 2412 ins at room ten	٠٢٠	<b></b>			

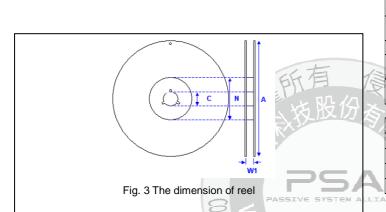
No.	Item	Test Conditi	on	Requirements		
12.	Temperature Cycle	* Conduct the five cycles according to time.    Step	Time (min.) 30±3 2~3 30±3 2~3	* No remarkable damage.  * Cap change:  NP0: within ±2.5% or ±0.25pF whichever is larger.  X7R: within ±7.5%  Y5V: within ±20%  * Q/D.F., I.R. and dielectric strength: To meet initial requirements.		
10		at 150°C for 1hr then set for 24±2 hrs * Cap. / DF(Q) / I.R. Measurement to at 150°C for 1hr then set for 24±2 hrs	at room temp. be made after de-aging			
13.	Humidity (Damp Heat) Steady State	* Test temp.: 40±2°C  * Humidity: 90~95% RH  * Test time: 500+24/-0hrs.  *Before initial measurement (Class II of at 150°C for 1hr then set for 24±2 hrs  * Cap. / DF(Q) / I.R. Measurement to at 150°C for 1hr then set for 24±2 hrs	at room temp. be made after de-aging	* No remarkable damage.  * Cap change: NP0: within ±5.0% or ±0.5pF whichever is larger.  X7R: within ±12.5%  Y5V: within ±30%  * Q/D.F. value:  NP0: Cap≥30pF, Q≥350; 10pF≤Cap<30pF, Q≥275+2.5C  Cap<10pF; Q≥200+10C  X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%  Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%  * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.		
14.	Humidity (Damp Heat) Load	* Test temp.: 40±2°C  * Humidity: 90~95%RH  * Test time: 500+24/-0 hrs.  * To apply voltage: rated voltage.  *Before initial measurement (Class II at 150°C for 1hr then set for 24±2 hrs  * Cap. / DF(Q) / I.R. Measurement to at 150°C for 1hr then set for 24±2 hrs	at room temp.	* No remarkable damage.  * Cap change: NP0: within ±7.5% or ±0.75pF whichever is larger.  X7R: within ±12.5%  Y5V: within ±30%  * Q/D.F. value:  NP0: Cap≥30pF, Q≥200; Cap<30pF, Q≥100+10/3C  X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%  Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%  * I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.		
15.	High Temperature Load (Endurance)	* Test temp.:  NP0, X7R: 125±3°C  Y5V: 85±3°C  * To apply voltage: 200% of rated volta  * Test time: 1000+24/-0 hrs.  *Before initial measurement (Class II of at 150°C for 1hr then set for 24±2 hrs  * Cap. / DF(Q) / I.R. Measurement to at 150°C for 1hr then set for 24±2 hrs	only): To apply de-aging at room temp . be made after de-aging	* No remarkable damage.  * Cap change: NP0: within ±3.0% or ±0.3pF whichever is larger.  X7R: within ±12.5%  Y5V: within ±30%  * Q/D.F. value:  NP0: Cap≥30pF, Q≥350  10pF≤Cap<30pF, Q≥275+2.5C  Cap<10pF, Q≥200+10C  X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%  Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%  * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.		

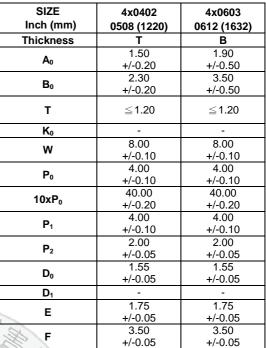
### <u>APPENDIXES</u>

#### **■ Tape & reel dimensions**

**Multilayer Ceramic Capacitors** 

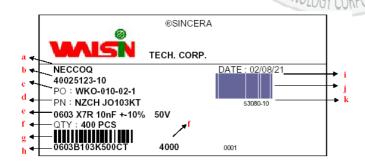






Reel size	7"
CO	13.0+0.5/-0.2
$W_1$	8.4+1.5/-0
A	178.0±1.0
N	60.0+1.0/-0

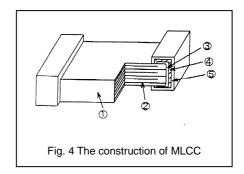
## **■** Description of customer label



- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- j. Order bar code including series and item numbers
- k. Serial number of label

#### Constructions

No.	Nan	ne	NP0, X7R, Y5V
①	Ceramic r	material	BaTiO₃ based
2	Inner ele	ctrode	Ni
3		Inner layer	Cu
4	Termination	Middle layer	Ni
(5)		Outer layer	Sn (Matt)



## **■** Storage and handling conditions

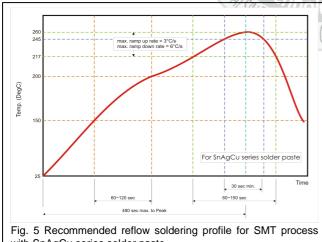
- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

#### Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

## ■ Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N<sub>2</sub> within oven are recommended.



with SnAgCu series solder paste.

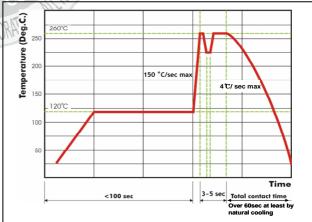


Fig. 6 Recommended wave soldering profile for SMT process with SnAgCu series solder.

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CKCL22X5R0J105M CKCL22X5R1A474M CKCL22X7R1H103M CKCL44C0G1H151K CKCL44X7R1C223M CKCM25C0G1H470K
CKCM25C0G1H680K CKCM25X5R0J474M CKCM25X5R1C223M CKCM25X7R1H222M W2L16C473MAT1S W2L16C683MAT1A
CKCM25X5R1A473M CKCM25X7R1H472M CKCM25X5R0J105M CKCL44X5R1A473M CKCL22X7R1H223M CKCL22X7R1H102M
CKCL22X5R1C224M CKCL22C0G1H470K CKCL22C0G1H221K CKCL22C0G1H151K W2L16C474MAT1A W2L14Z225MAT1A
2255-126-15636 W2L1YC104MAT1F CA064X102K1RACTU CA064X102K3RACTU CA064X102K4RACTU CA064X150J5GACTU
CA064X151J5GACTU CA064X181J5GACTU CA064X331J5GACTU CA064X391J5GACTU NCA0805NPO470K50TRPF
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CA0612KRX7R9BB103 CA064C103M5RACTU CA064C330K5GACTU 20108D1X103K5E